











PRODUCT DATASHEET



- ► EMC SMD Top View
- ➤ 3838 1.51t Series
- ► Infrared (IR) 850nm

NOF60S75BF





3838 1.51t Series

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FEATURES:

Package: Black Ceramic Dual Junction SMT Package

Forward Current: 1000~1500mA Pulse Forward Current (max.): 5A

Forward Voltage (typ.): 3.2V

Radiant Power (typ.): 1360mW@1A; 1950mW@1.5A

Radiant Intensity (typ.): 350mW/sr@1A; 520mW/sr@1.5A

Colour: Infrared (IR)

Peak Wavelength (typ.): 850nm

Viewing angle: 150°

Operating Temperature: -40~+125°C Storage Temperature: -40~+125°C

Grouping Parameters:

Forward Voltage

Radiant Power

Peak Wavelength

Soldering Methods: Reflow Soldering

MSL Level: MSL 2 according to J-STD020

Corrosion Robustness Class: 3B

Packing: 12mm tape with max.800/reel, ø178mm (7")

APPLICATIONS:

- Automotive
- Security Camera
- **Motion Detection**
- Night Viewer
- Surveillance
- **Data Communication**



CHARACTERISTICS:

Absolute Maximum Characteristics (T_a=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	l _F	1500	mA
Pulse Forward Current	IPF	5	А
Power Consumption	P _{tot}	5.7	W
Reverse Voltage	V _R	5	V
Reverse Current @5V	I _R	10	μΑ
Junction Temperature	Tj	145	°C
Thermal Resistance Junction to Solder Point	R _{th}	typ. 4.5; max. 9	K/W
Electrostatic Discharge (HBM: MIL-STD-883 C 2)	ESD	2	kV
Operating Temperature	T _{OPR}	-40~+125	°C
Storage Temperature	T _{STG}	-40~+125	°C
Soldering Temperature	T _{SOL}	260	°C



Electrical & Optical Characteristics (T_a=25°C, I_F=1A, t_p=10ms)

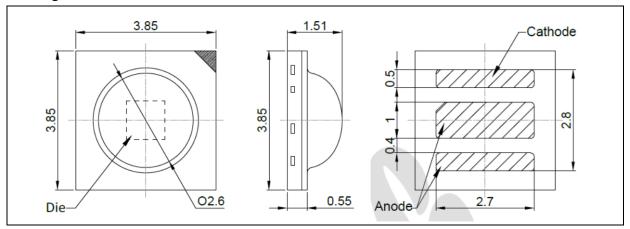
Darameter	Cumbal	Values			Unit	Test
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
		2.8	3.2	3.6		I _F =1A
		2.8				t _p =100μs
Forward Voltage	V_{F}	3.0	3.4	3.8	V	I _F =1.5A
Torward voitage	V F	3.0			ľ	t _p =100μs
			4.4	5.0		I _F =5A
			7.7	5.0		t _p =100μs
		1100	1360	1600		I _F =1A
Radiant Power	Фе	1100			mW	t _p =100μs
Radialit Powel	Ψe	1700	1950	2200		I _F =1.5A
						t _p =100μs
	I _e	250	350	450	mW/sr	I _F =1A
Radiant Intensity		230				t _p =100μs
		420	520	620		I _F =1.5A
			320	020		t _p =100μs
Peak Wavelength	Λ_{P}		850		nm	I _F =1A
Spectral Bandwidth	Δλ		35		nm	I _F =1A
Viewing Angle	2θ _{1/2}		150		deg	I _F =1A

^{1.} Radiant Power (Po) $\pm 10\%$, Forward Voltage (V_F) ± 0.1 V, Viewing angle($2\theta_{1/2}$) $\pm 10^\circ$



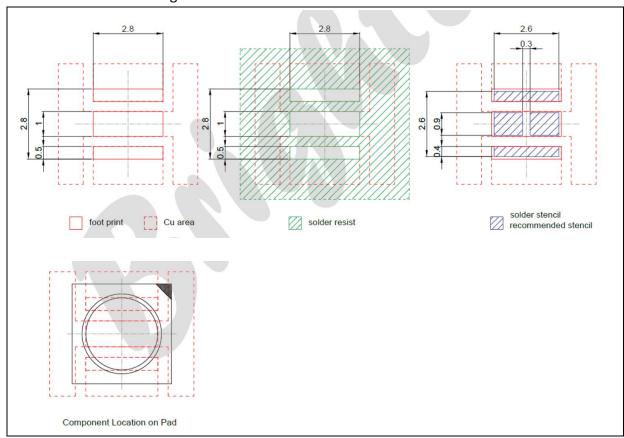
OUTLINE DIMENSION:

Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.13mm, unless otherwise noted.

Recommended Soldering Pad Dimension:



- 1. Dimensions are in millimetre (mm).
- 2. Tolerance ±0.1mm with angle tolerance ±0.5°.



BINNING GROUPS:

Forward Voltage Classifications (I_F=1A; t_p=10ms):

Code	Min.	Max.	Unit
KN	2.8	3.6	V

Radiant Power Classifications (I_F=1A; t_p=10ms):

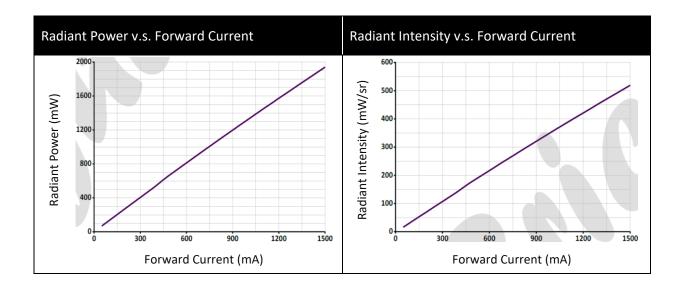
Code	Min.	Max.	Unit
PB1A	1100	1300	
PB3A	1300	1500	mW
PB5	1500	1600	

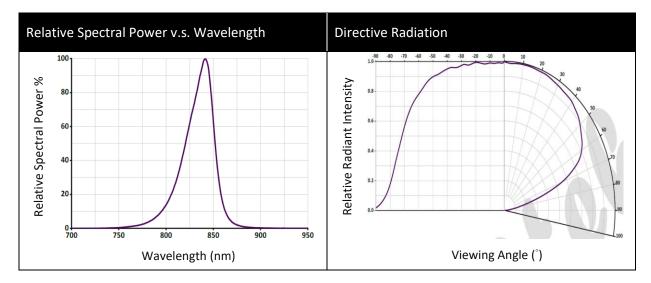
Peak Wavelength Classifications (I_F=1A; t_p=10ms):

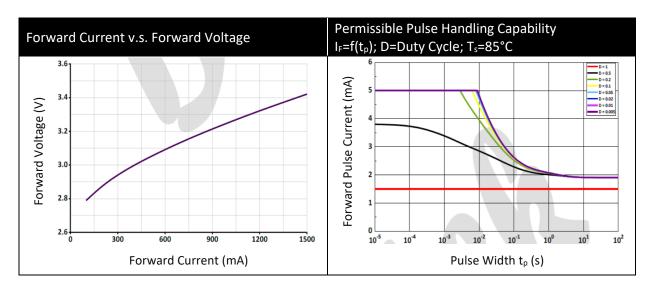
Code	Min.	Max.	Unit
F3	840	870	nm



ELECTRO-OPTICAL CHARACTERISTICS:

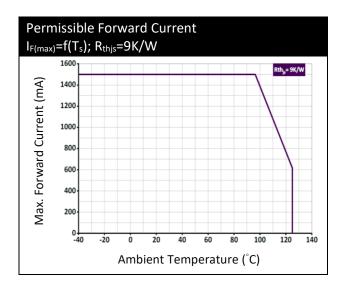








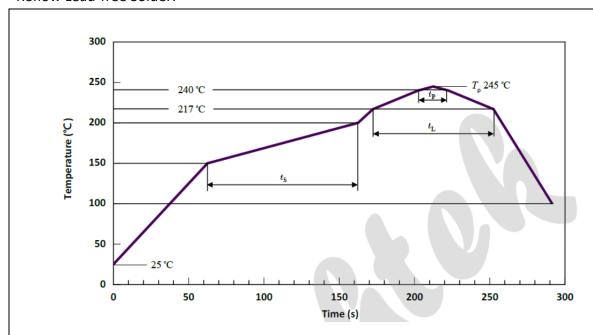
ELECTRO-OPTICAL CHARACTERISTICS:





RECOMMENDED SOLDERING PROFILE:

Reflow Lead-free Solder:



Profile Feature	Symbol	Pb-Free (SnAgCu) Assembly			Unit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat 25 °C to 150 °C		V	2	3	K/s
Time ts T _{Smin} to T _{Smax}	ts	60	100	120	s
Ramp-up rate to peak T _{Smax} to T _P			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	tL		80	100	s
Peak temperature	Тр		245	260	°C
Time within 5 °C of the specified peak temperature TP - 5 K	ТР	10	20	30	s
Ramp-down Rate			3	4	V /-
T _P to 100 °C			3	4	K/s
Time 25 °C to T _P				480	s

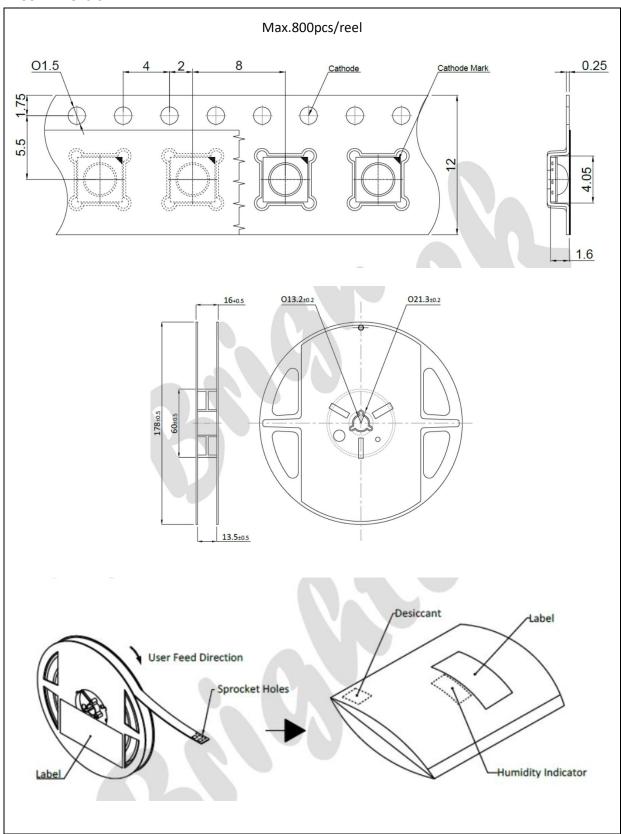
Note:

- 1. Maximum reflow soldering: 2 times.
- 2. Recommended soldering temperature is 245°C. The maximum soldering temperature should be limited to 260°C.
- 3. Before, during, and after soldering, should not apply stress on the components and PCB board.



PACKING SPECIFICATION:

Reel Dimension:





PRECAUTIONS OF USE:

Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

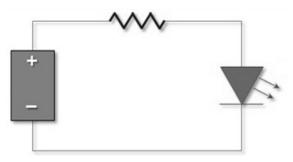
Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 60±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

Testing Circuit:



Must apply resistor(s) for protection (over current proof).

Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.



REVISION RECORD:

Version	Date	Summary of Revision	
A1.0	22/05/2022	Datasheet set-up.	
A1.1	05/09/2024	Add packing and binning information.	